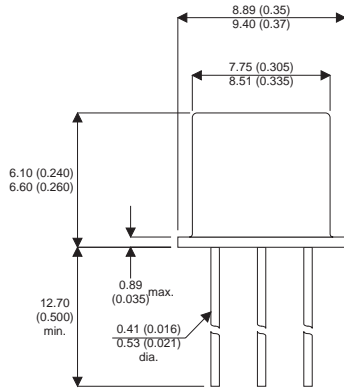


**MECHANICAL DATA**

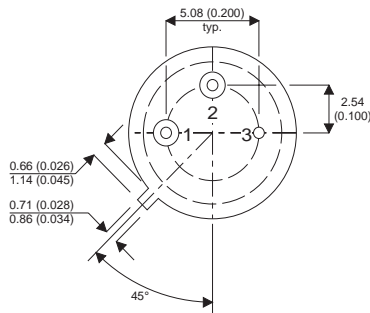
Dimensions in mm( inches)



**NPN SILICON TRANSISTOR**

**FEATURES**

- FAST SWITCHING
- HIGH PULSE POWER



**TO39**

**APPLICATIONS**

- POWER SWITCHING CIRCUITS
- MOTOR CONTROL

Pin 1 = Emitter    Pin 2 = Base    Pin 3 = Collector

**ABSOLUTE MAXIMUM RATINGS** ( $T_{case} = 25^{\circ}C$  unless otherwise stated)

$V_{CBO}$	Collector – Base Voltage	100V
$V_{CEO}$	Collector – Emitter Voltage	80V
$V_{EBO}$	Emitter – Base Voltage	5V
$I_C$	Collector Current	3A
$I_B$	Base Current	2A
$P_{tot}$	Total Power Dissipation at $T_{case} \leq 25^{\circ}C$	1W
$T_{amb}$	Ambient Operating Temperature	-55°C to +200°C
$T_{stg}$	Storage Temperature	-55°C to +200°C

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.

**ELECTRICAL CHARACTERISTICS** ( $T_{amb} = 25^{\circ}\text{C}$  unless otherwise stated)

Parameter	Test Conditions	Min.	Typ.	Max.	Unit	
$h_{21E}$	Static Value of Common Emitter Forward Current Transfer Ratio	$V_{CE} = 10\text{V}$ $I_C = 0.15$	50		250	—
		$V_{CE} = 10\text{V}$ $I_C = 2\text{A}$	15			
		$V_{CE} = 10\text{V}$ $I_C = 1\text{mA}$	20			
$f_T$	Transistion Frequency	$V_{CE} = 5\text{V}$ $f = 20\text{MHz}$	$I_C = 100\text{mA}$	50		MHz
$I_{CBO}$	Collector Base Cut- Off Current.	$V_{CB} = 80\text{V}$	$I_E = 0$		100	nA
			$t = 150^{\circ}\text{C}$		100	$\mu\text{A}$
$I_{EBO}$	Emitter–Base Cut-off Current	$V_{EB} = 4\text{V}$			100	nA
$h_{21e}$	Small Signal Common Emitter Forward Current Transfer Ratio	$V_{CE} = 5\text{V}$ $f = 1\text{KHz}$	$I_C = 10\text{mA}$	25		—
$V_{CE(sat)^*}$	Collector – Emitter Saturation Voltage*	$I_C = 150\text{mA}$ $I_C = 1\text{A}$	$I_B = 15\text{mA}$		0.3	V
			$I_B = 0.1\text{A}$		0.6	
$V_{BE(sat)^*}$	Base – Emitter Saturation Voltage*	$I_C = 150\text{mA}$ $I_C = 1\text{A}$	$I_B = 15\text{mA}$		0.95	V
			$I_B = 0.1\text{A}$		1.3	
$C_{22b}$	Common – Base Output Capacitance	$V_{CB} = 10\text{V}$ $f = 1\text{MHz}$	$I_E = 0$		80	pF

\*Pulse Conditions: Pulse Length =  $300\mu\text{s}$  duty cycle = 1.5%